NSN 5961-01-359-2019

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-359-2019 **Inclosure Material:** Glass **Overall Length:** 0.160 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.075 inches **Mounting Method:** Terminal **Features Provided:** Electrostatic sensitive **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 reverse voltage, peak **Current Rating Per Characteristic:** 150.00 milliamperes forward current, average absolute **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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